

# M74HC4852

## Dual 4:1 channel analog MUX/DEMUX with injection current protection

#### Datasheet – production data

## Features

- Low power dissipation
  - I<sub>CC</sub> = 2 µA (max.) at T<sub>A</sub> = 25 °C
- Injection current protection: V<sub>Δ</sub>out < 1 mV at V<sub>CC</sub> = 5 V, I<sub>IN</sub> = 1 mA, R<sub>S</sub> = 3.9 kΩ
- "ON" resistance at T<sub>A</sub> = 25 °C
  - $-215 \Omega$  typ. (V<sub>CC</sub> = 3.0 V)
  - 160  $\Omega$  typ. (V<sub>CC</sub> = 4.5 V)
  - 150  $\Omega$  typ. (V<sub>CC</sub> = 6 V)
- Fast switching: t<sub>pd</sub> = 8.6 ns (typ.) at T<sub>A</sub> = 25 °C, V<sub>CC</sub> = 4.5 V
- Wide operating supply voltage range

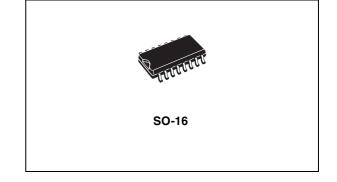
- 
$$V_{CC} = 2 V \text{ to } 6 V$$

- High noise immunity: V<sub>NIH</sub> = V<sub>NIL</sub> = 28% V<sub>CC</sub> (min.)
- Pin and function compatible with series 4052, 4852
- Latch-up performance exceeds 500 mA
   (JESD 17)
- ESD performance
  - HBM: 2000 V
  - MM: 200 V
  - CDM: 1000 V

## Applications

- Automotive
- Computer
- Consumer
- Industrial

#### Table 1.Device summary



## Description

The M74HC4852 device is a dual four-channel analog multiplexer/demultiplexer manufactured with silicon gate C<sup>2</sup>MOS technology.

It features injection current effect control which makes the device particularly suited for use in automotive applications where voltages in excess of normal logic voltage are common. The injection current effect control allows signals at disabled input channels to exceed the supply voltage range or go down to ground without affecting the signal of the enabled analog channel.

This eliminates the need for external dioderesistor networks typically used to keep the analog channel signals within the supply voltage range.

Order code	Temperature range	Package	Packaging	Marking
M74HC4852RM13TR	-55/+125 °C	SO16	Tape and reel	74HC4852
M74HC4852YRM13TR <sup>(1)</sup>	-40/+125 °C	SO16 (automotive grade)	Tape and reel	74HC4852Y

1. Qualification and characterization according to AEC Q100 and Q003 or equivalent, advanced screening according to AEC Q001 and Q002 or equivalent.

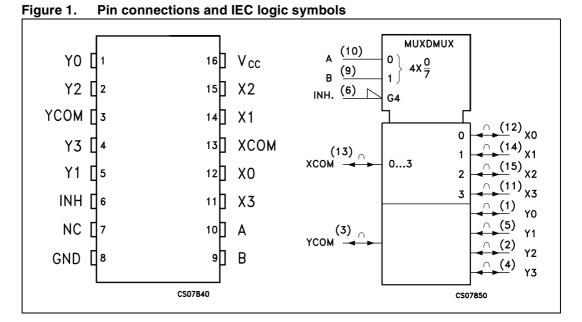
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This is information on a product in full production.

## 1 Pin connections



### Table 2. Pin descriptions

Pin number	Symbol	Name and function
3, 13	YCOM, XCOM	Common output/input
6	INH	INHIBIT input
7	NC	Not connected
10, 9	А, В	Select inputs
12, 14, 15, 11, 1, 5, 2, 4	X0 to X3, Y0 to Y3	Independent input/outputs
8	GND	Ground (0 V)
16	V <sub>CC</sub>	Positive supply voltage

#### Table 3. Truth table

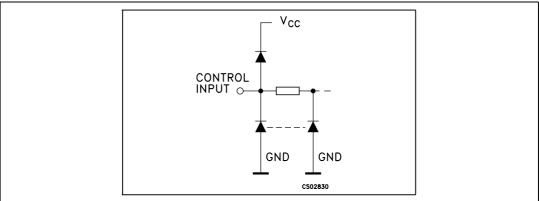
	Input state	On channel				
INH	В	Α				
L	L	L	X0	Y0		
L	L	Н	X1	Y1		
L	Н	L	X2	Y2		
L	Н	Н	X3	Y3		
Н	х	Х	NONE	NONE		

Note: X: don't care.

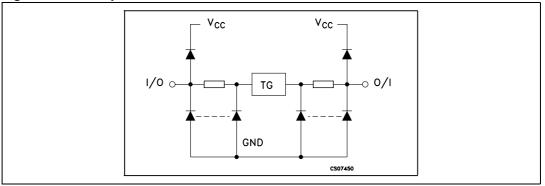
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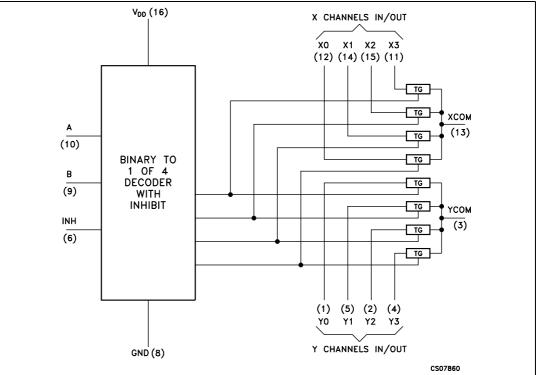




### Figure 3. I/O equivalent circuit









## 2 Absolute maximum ratings and operating conditions

Note: Absolute maximum ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied.

Symbol	Paran	neter	Value	Unit
V <sub>CC</sub>	Supply voltage		-0.5 to +7	V
V <sub>IN</sub>	Control input voltage	-0.5 to V <sub>CC</sub> + 0.5	V	
V <sub>I/O</sub>	Switch I/O voltage	-0.5 to V <sub>CC</sub> + 0.5	V	
I <sub>CK</sub>	Control input diode current	± 25	mA	
I <sub>IOK</sub>	I/O diode current	± 25	mA	
I <sub>CC</sub>	DC V <sub>CC</sub> or ground current		± 50	mA
PD	Power dissipation	SO-16	500 <sup>(1)</sup>	mW
T <sub>stg</sub>	Storage temperature		-65 to +150	°C
ΤL	Lead temperature (10 sec.)		300	°C
	Human body model (HBM)	Human body model (HBM)		V
ESD (JESD22)	Machine model (MM)	200	V	
(020022)	Charged device model (CDM)		1000	V

#### Table 4. Absolute maximum ratings

1. Power dissipation at 65 °C. Derating from 65 °C to 125 °C: SO package -7 mW/°C.

#### Table 5. Recommended operating conditions

Symbol	Parameter		Value	Unit
V <sub>CC</sub>	Supply voltage		2 to 6	V
V <sub>I/O</sub>	Input output voltage		0 to V <sub>CC</sub>	V
V <sub>I/O</sub>	Static or dynamic voltage across switch	h <sup>(1)</sup>	0 to 1.2	V
V <sub>IN</sub>	Control input voltage	0 to V <sub>CC</sub>	V	
Ŧ		SO16	-55 to +125	°C
T <sub>op</sub>	Operating temperature	SO16 (automotive grade)	-40 to +125	°C
		V <sub>CC</sub> = 2.0 V	0 to 1000	ns
		V <sub>CC</sub> = 3.0.V	0 to 800	
t <sub>r</sub> , t <sub>f</sub>	Input rise and fall time <sup>(2)</sup> (channel select or enable inputs only)	V <sub>CC</sub> = 3.3 V	0 to 700	
		V <sub>CC</sub> = 4.5 V	0 to 500	
		V <sub>CC</sub> = 6.0 V	0 to 400	

For voltage drops across the switch greater than 1.2 V (switch on), excessive V<sub>CC</sub> current may be drawn; i.e., the current
out of the switch may contain both V<sub>CC</sub> and switch input components. The reliability of the device is unaffected unless the
maximum ratings are exceeded.

2.  $V_{IN}$  from 30% to 70%  $V_{CC}$  of channel selected or enable inputs.



			Test con	dition				Value	e			
Symbol	Parameter	v <sub>cc</sub>			Т,	A = 25	°C	Up to	85 °C	Up to	125 °C	Unit
		(V)			Min.	Тур.	Max.	Min.	Max.	Min.	Max.	
		2.0			1.5			1.5		1.5		
		3.0			2.1			2.1		2.1		
V <sub>IHC</sub>	High level input voltage	3.0			2.3			2.3		2.3		V
	, , , , , , , , , , , , , , , , , , ,	4.5			3.15			3.15		3.15		
		6.0			4.2			4.2		4.2		
		2.0					0.5		0.5		0.5	
		3.0					0.9		0.9		0.9	
V <sub>ILC</sub>	Low level input voltage	3.3					1.0		1.0		1.0	V
		4.5					1.35		1.35		1.35	
		6.0					1.8		1.8		1.8	
		2.0	$I_S = 2 \text{ mA}$ $I_S \le 2 \text{ mA}$			500	650		670		700	Ω
		3.0		$V_{IN} = V_{IHC}$		215	280		320		360	
R <sub>ON</sub>	ON resistance	3.3		or V <sub>ILC</sub> V <sub>IS</sub> = V <sub>CC</sub> to GND		210	270		305		345	
		4.5				160	210		240		270	
		6.0				150	195		220		250	
		2.0	$I_S = 2 \text{ mA}$			4	10		15		20	
	Difference of	3.0		V – V		2	8		12		16	Ω
$\Delta R_{ON}$	ON resistance between	3.3	L < 0 m 4	$V_{IN} = V_{IHC}$ or $V_{ILC}$ $V_{IS} = V_{CC}/2$		2	8		12		16	
	switches	4.5	IS≥ZIIIA	$V_{IS} = V_{CC}/2$		2	8		12		16	
		6.0				3	9		13		18	
I <sub>OFF</sub>	Input/output leakage current (switch off) (any channel)	6.0					±0.1		±0.5		±1.0	μΑ
I <sub>OFF</sub>	Input/output leakage current (switch off) (common channel)	6.0	V <sub>IN</sub> = V <sub>CC</sub> or GND				±0.2		±2		±4	μA
I <sub>ON</sub>	Switch input leakage current (switch on, output open)	6.0	V <sub>IN</sub> = V <sub>0</sub>	<sub>CC</sub> or GND			±0.1		±0.5		±1	μΑ

## Table 6.DC specifications



	Test condition		Value								
Symbol Parameter		v <sub>cc</sub>		Τ,	T <sub>A</sub> = 25 °C		Up to 85 °C		Up to 125 °C		Unit
	(V)			Min.	Тур.	Max.	Min.	Max.	Min.	Max.	
I <sub>IN</sub>	Control input current	6.0	$V_{IN} = V_{CC}$ or GND			±0.1		±0.1		±1	μA
ICC	Quiescent supply current	6.0	V <sub>IN</sub> = V <sub>CC</sub> or GND V <sub>IN (analog)</sub> = GND			2		20		40	μA

## Table 6. DC specifications (continued)

## Table 7.AC electrical characteristics ( $C_L = 50 \text{ pF}$ , input $t_r = t_f = 6 \text{ ns}$ )

			Test condition				Value	)			
Symbol	Parameter	v <sub>cc</sub>	To at almostic d	T <sub>A</sub> = 25 °C		Up to	85 °C	Up to	125 °C	Unit	
		(V)	Test circuit 1	Min.	Тур.	Max.	Min.	Max.	Min.	Max.	
		2.0			19.5	25		29		32	
	Propagation	3.0			12	15.5		17.5		19.5	
t <sub>PHL,</sub> t <sub>PLH</sub>	delay time, analog input to	3.3			11	14.5		16.5		18.5	ns
	analog output	4.5			8.6	11.5		12.5		13.5	
		6.0			8	10		11		12	
		2.0			23	30		35		40	
	Propagation	3.0			13.5	17.5		20		23	ns
t <sub>PHL,</sub> t <sub>PLH</sub>	delay time channel-select	3.3			12.5	16.5		19		22	
	to analog output	4.5			10	13		15		17	
		6.0			9.5	12.5		14.5		16.5	
		2.0				95		105		115	
t <sub>PHZ</sub> ,	Enable disable	3.0				90		100		110	
t <sub>PZH</sub> t <sub>PLZ,</sub> ,	time, enable or channel-select	3.3				85		95		105	ns
t <sub>PZL</sub>	to analog output	4.5				80		90		100	
		6.0				78		80		80	
C <sub>IN</sub>	Input capacitance (digital pins)				3.5	10		10		10	pF
C <sub>IN</sub>	Input capacitance (switches off, any single analog pins)				6.7	15		15		15	pF



		Test condition		Value							
Symbol	Parameter	Vcc	V <sub>CC</sub> (V) Test circuit 1	T <sub>A</sub> = 25 °C			Up to 85 °C		Up to 125 °C		Unit
		(V)		Min.	Тур.	Max.	Min.	Max.	Min.	Max.	
C <sub>IN</sub>	Input capacitance (switches off, any common analog pins)				22	40		40		40	pF
Power		3.3			24						-
C <sub>PD</sub>	dissipation capacitance <sup>(1)</sup>	5.0			28						pF

### Table 7.AC electrical characteristics ( $C_L = 50 \text{ pF}$ , input $t_r = t_f = 6 \text{ ns}$ ) (continued)

1.  $C_{PD}$  is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load (refer to *Figure 5*). The average operating current can be obtained by the following equation:  $I_{CC}$  (opr.) =  $C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/8$ .

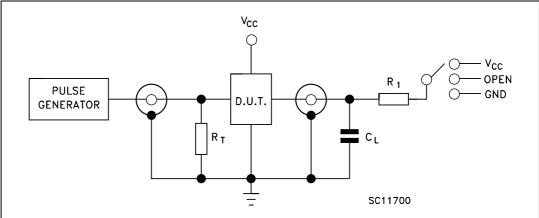
### Table 8. Injection current coupling specification (T<sub>A</sub>= -55 °C to +125 °C)

		Те	st condition	Va	lue	
Symbol	Parameter	V <sub>CC</sub> (V)	Test circuit 2	Typ. <sup>(1)</sup>	Max.	Unit
		3.3	$I_{IN} \leq 1 \text{ mA}, R_S \leq 3.9 \text{ k}\Omega$	0.050	1.0	
	5.0	$I_{\rm IN} \ge 1$ IIIA, $H_{\rm S} \ge 3.9$ K22	0.100	1.0		
	Ohift of output	3.3	l <sub>IN</sub> ≤ 10 mA, R <sub>S</sub> ≤ 3.9 kΩ	0.345	5.0	mV
V	Shift of output voltage of	5.0	$I_{\rm N} \ge 10$ IIIA, $R_{\rm S} \ge 3.8$ K22	0.067	5.0	
V <sub>∆OUT</sub>	enabled analog channel	3.3	I <sub>IN</sub> ≤ 1 mA, R <sub>S</sub> ≤ 20 kΩ	0.050	2.0	111.0
	channel	5.0	$I_{N} \ge I IIIA, \Pi_{S} \ge 20 \text{ km}$	0.110	2.0	1
		3.3	$L \leq 10 \text{ mA} \text{ R} \leq 20 \text{ kO}$	0.050	20	
		5.0	$I_{\rm IN} \le 10$ mA, R <sub>S</sub> $\le 20$ k $\Omega$ = 5.0		20	

1. Typical values are measured at  $T_A = 25 \text{ °C}$ . They are calculated as the difference from  $V_{OUT}$  without injection current and  $V_{OUT}$  with injection current. I<sub>IN</sub> = total current injected into any other disabled channels, one at time.



Figure 5. **Test circuit 1** 



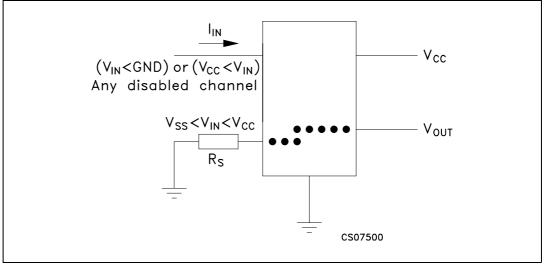
#### Table 9. Test circuit 1 - switch configuration table

Test	Switch
t <sub>PLH</sub> , t <sub>PHL</sub>	Open
t <sub>PZL</sub> , t <sub>PLZ</sub>	V <sub>CC</sub>
t <sub>PZH</sub> , t <sub>PHZ</sub>	GND

Note:

 $C_L = 50 \text{ pF}$  or equivalent (includes jig and probe capacitance).  $R_L = R1 = 10 \text{ k}\Omega$  or equivalent.  $R_T = Z_{OUT}$  of pulse generator (typically 50  $\Omega$ ).







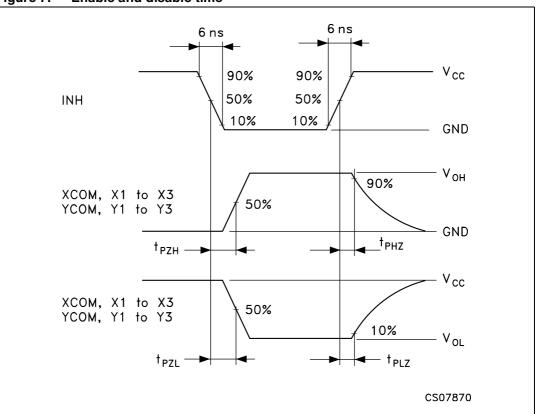
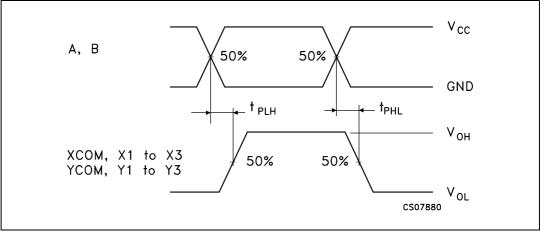


Figure 7. Enable and disable time









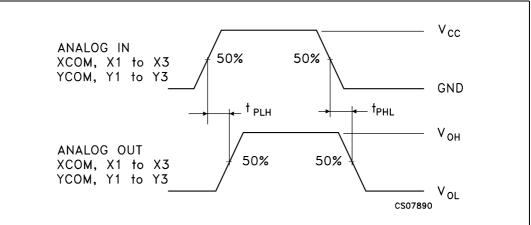
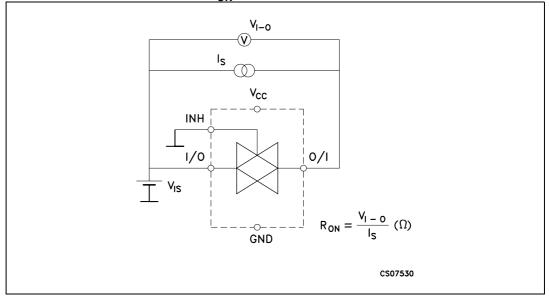
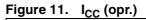
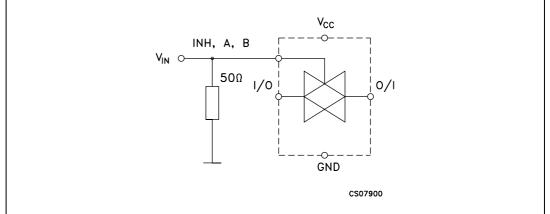


Figure 10. Channel resistance R<sub>ON</sub>









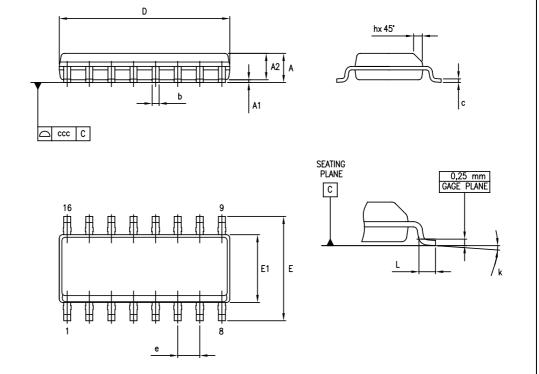
## 3 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK is an ST trademark.



## 3.1 SO-16 package information





### Table 10. SO-16 package mechanical data

	Dimensions									
Symbol		Millimeters			Inches					
	Min. Typ. N		Max.	Min.	Тур.	Max.				
А			1.75			0.069				
A1	0.10		0.25	0.004		0.010				
A2	1.25			0.049						
b	0.31		0.51	0.012		0.020				
С	0.17		0.25	0.007		0.010				
D	9.80	9.90	10.00	0.386	0.390	0.394				
E	5.80	6.00	6.20	0.228	0.236	0.244				
E1	3.80	3.90	4.00	0.150	0.154	0.157				
е		1.27			0.050					
h	0.25		0.50	0.010		0.020				
L	0.40		1.27	0.016		0.050				
k	0		8							
ccc			0.10			0.004				



## 4 Ordering information

### Table 11. Order codes

Order code	Temperature range	Package	Packaging	Marking
M74HC4852RM13TR	-55/+125 °C	SO-16	Tape and reel	74HC4852
M74HC4852YRM13TR <sup>(1)</sup>	-40/+125 °C	SO-16 (automotive grade)		74HC4852Y

1. Qualification and characterization according to AEC Q100 and Q003 or equivalent, advanced screening according to AEC Q001 and Q002 or equivalent.



**1**.)

# 5 Revision history

Date	Revision	Changes	
05-Apr-2012	5	Document reformatted. Added ESD charged device model feature on cover page. Added ESD values to <i>Table 4: Absolute maximum ratings</i> . Modified <i>Chapter 3: Package information</i> . Modified <i>Chapter 4: Ordering information</i> .	
15-Jun-2012	6	Corrected ON-resistance values in <i>Features on page 1</i> Added <i>Applications on page 1</i> Shortened <i>Description on page 1</i> Added <i>Table 1: Device summary on page 1</i> Updated T <sub>op</sub> in <i>Table 5: Recommended operating conditions</i> Updated <i>Table 11: Order codes on page 13</i>	
18-Oct-2012	7	Updated ESD values in <i>Features</i> . Updated <i>Table 1</i> (added Packaging and Marking, updated not Updated <i>Table 11</i> (updated note <i>1</i> ). Minor corrections throughout document.	

### Table 12.Document revision history



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